

DN030S

NPN Silicon Transistor

PIN Connection

3

SOT-23F

Base

Features

- Extremely low collector-to-emitter saturation voltage
 - $(V_{CE(SAT)} = 0.1V \text{ Typ. } @I_{C}/I_{B} = 100\text{mA}/10\text{mA})$
- Suitable for low voltage large current drivers
- Complementary pair with DP030S
- Switching Application

Ordering Information

0		
Type NO.	Marking	Package Code
DN030S	<u>N01</u> □ ① ②	SOT-23F

¹⁾ Device Code 2) Year&Week Code

Absolute maximum ratings

(Ta=25°C)

Collector

Emitter

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V _{CBO}	15	V
Collector-Emitter voltage	V _{CEO}	12	V
Emitter-Base voltage	V_{EBO}	5	V
Collector current	Ic	300	m A
Collector dissipation	P _C	200	m W
Junction temperature	T _j	150	°C
Storage temperature	T_{stg}	-55~ 150	°C

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV _{CBO}	$I_C = 50 \mu A, I_E = 0$	15	-	-	V
Collector-Emitter breakdown voltage	BV _{CEO}	$I_{C} = 1 \text{ m A}, I_{B} = 0$	12	1	-	V
Emitter-Base breakdown voltage	BV _{EBO}	$I_E = 50 \mu A, I_C = 0$	5	-	-	V
Collector cut-off current	I _{CBO}	$V_{CB} = 12V, I_{E} = 0$	-	-	0.1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = 5V, I_{C} = 0$	-	-	0.1	μΑ
DC average rain	h _{FE1}	V _{CE} = 1V, I _C = 100mA	200	-	450	-
DC current gain	h _{FE2}	$V_{CE} = 1V, I_{C} = 300 \text{ m A}$	70	-	-	-
Collector Emitter acturation valtage	V _{CE(sat1)}	I _C = 100mA, I _B = 10mA	-	•	0.2	V
Collector-Emitter saturation voltage	V _{CE(sat2)}	$I_{C} = 300 \text{ mA}, I_{B} = 30 \text{ mA}$	-	-	0.5	V
Page Emitter esturation voltage	V _{BE(sat1)}	$I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$	-	-	1.2	V
Base-Emitter saturation voltage	V _{BE(sat2)}	$I_{C} = 300 \text{ mA}, I_{B} = 30 \text{ mA}$	-	-	1.7	V
Transition frequency	f _T	$V_{CE} = 5V, I_{C} = 10 \text{ m A}$	-	300	-	MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	-	3	-	PF

KSD-T5C008-000

Electrical Characteristic Curves

Fig. 1 P_C - T_a

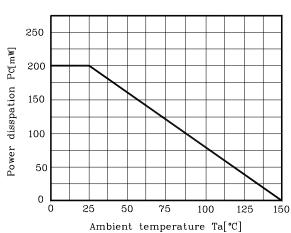


Fig. 2 I_C - V_{BE}

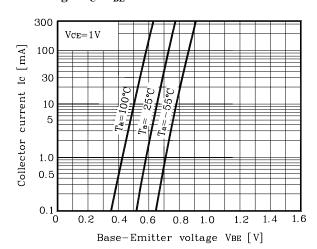


Fig. 3 $h_{FE}\$ - $\ I_{C}$

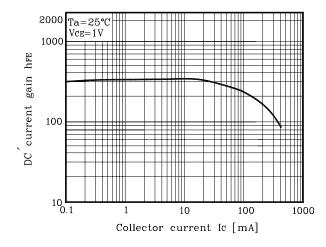


Fig. 4 I_C - V_{CE}

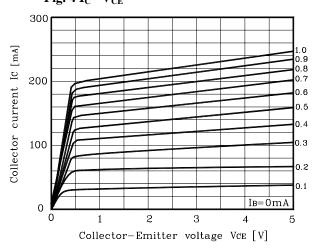
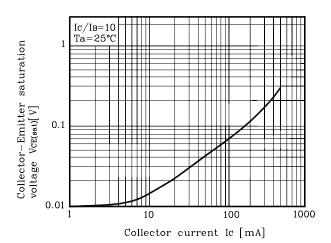
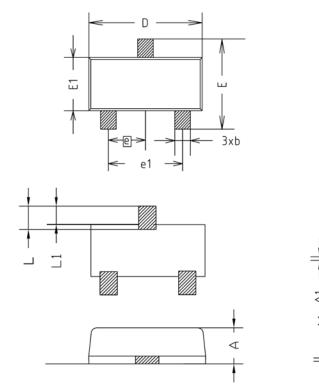


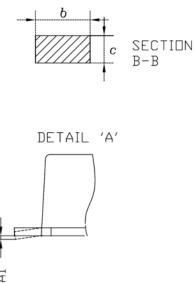
Fig. 5 $V_{\text{CE}(\text{sat})}$ - I_{C}



KSD-T5C008-000 2

Outline Dimension

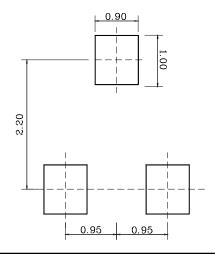




SEE DETAIL 'A'

	MILLIMETER(mm)			
SYMBOL	MINIMUM			NOTE
Α	0.80	0.90	1.00	
A1	0.00	-	0.10	
b	0.35	0.40	0.45	
C	0.10	0.15	0.20	
D	2.80	2.90	3.00	
Ε	2.30	2.40	2.50	
E1	1.50	1.60	1.70	
е	0.95BSC			
e1	1.80	1.90	2.00	
L	0.48	0.58	0.68	
L1	0.30	-	0.50	

*Recommend PCB solder land [Unit: mm]



The AUK Corp. products are intended for the use as components in general electronic equipment (Office and communication equipment, measuring equipment, home appliance, etc.).

Please make sure that you consult with us before you use these AUK Corp. products in equipments which require high quality and / or reliability, and in equipments which could have major impact to the welfare of human life(atomic energy control, airplane, spaceship, transportation, combustion control, all types of safety device, etc.). AUK Corp. cannot accept liability to any damage which may occur in case these AUK Corp. products were used in the mentioned equipments without prior consultation with AUK Corp..

Specifications mentioned in this publication are subject to change without notice.

KSD-T5C008-000